

# Improved conductivity in dye-sensitised solar cells through block-copolymer confined TiO<sub>2</sub> crystallisation

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**Abstract**

Anatase TiO<sub>2</sub> is typically a central component in high performance dye-sensitised solar cells (DSCs). This study demonstrates the benefits of high temperature synthesised mesoporous titania for the performance of solid-state DSCs. In contrast to earlier methods, the high temperature stability of mesoporous titania is enabled by the self-assembly of the amphiphilic block copolymer polyisoprene-*block*-polyethylene oxide (PI-*b*-PEO) which compartmentalises TiO<sub>2</sub> crystallisation, preventing the collapse of porosity at temperatures up to 700 °C. The systematic study of the temperature dependence on DSC performance reveals a parameter trade-off: while high temperature annealed anatase consisted of larger crystallites and had a higher conductivity, this came at the expense of a reduced specific surface area. While the reduction in specific surface areas was found to be detrimental for liquid-electrolyte DSC performance, solid-state DSCs benefitted from the increased anatase conductivity and exhibited a performance increase by a factor of three.

## Introduction

The interest in nanocrystalline, mesoporous TiO<sub>2</sub> has emerged in recent years for a variety of “green” applications such as dye-sensitised solar cells (DSCs),<sup>1</sup> photocatalysis,<sup>2</sup> electrochemical capacitors,<sup>3</sup> sensors,<sup>4</sup> and electrochromic devices.<sup>5</sup> Traditionally, mesoporous TiO<sub>2</sub> is obtained by sintering a random network of 10-20 nm sized particles which are derived by sol-gel chemistry.<sup>6</sup> The high surface area of these films is decisive for interface sensitive applications. Other important material properties include a large electronic band-gap, long-term stability against corrosion and a high surface affinity for dyes. The use of a network of randomly sintered particles has drawbacks, however. While the electron mobility in crystalline anatase TiO<sub>2</sub> is usually on the order of  $\mu \sim 10 \text{ cm}^2/\text{Vs}$ , this value decreases by five to six orders of magnitude in nanoparticle films.<sup>7,8</sup> The low electron mobility in nanoparticle TiO<sub>2</sub> films appears to limit charge collection and thereby power conversion efficiency in solid-state DSCs.<sup>9</sup> Furthermore, the lack of control over the pore size distribution may hinder pore infiltration by the viscous materials required to assemble this promising type of DSCs.<sup>10</sup> Controlling the morphology and crystallinity on the 10 nm length scale in TiO<sub>2</sub> films are therefore key factors for further development. A promising recipe for the synthesis of TiO<sub>2</sub> with better controlled pore structures involves block copolymer directed self-assembly of the titania sol. Wiesner and coworkers<sup>11</sup> as well as Stucky and coworkers<sup>12</sup> pioneered this sol-gel approach for silica, which was subsequently extended to other ceramics.<sup>13</sup> Titania has attracted particular interest by a large number of groups.<sup>13-16</sup> In these material systems, a sol selectively swells one part of an amphiphilic block-copolymer which typically microphase separates into ordered domains on the 5 to 50 nm length-scale. The incorporated inorganic material benefits therefore from the structure-directing property of the macromolecule even after the polymer is removed in a high temperature annealing step. Several groups have successfully used the structure directing agent Pluronic P123 (BASF) to derive mesoporous titania for dye sensitised photovoltaics,<sup>17,18</sup> but several challenges remain, especially for solid-state devices. The synthesis is rather time-consuming due to the slow self-assembly process and can take several days.<sup>14</sup> In order to prevent structural collapse, calcination is typically carried out at temperatures around 400 °C

which leads to poor crystallinity (less than 50%<sup>19,20</sup>) in comparison to sintered nanoparticle films. Ozin and coworkers studied the evolution of P123-derived crystallinity in-situ during the annealing process.<sup>19</sup> Transformation into a fully crystalline material at high annealing temperatures leads to the collapse of the structure.<sup>20</sup> This can be attributed to the fact that nanocrystals grow at typical crystallisation temperatures to diameters of 10-20 nm, which by far exceed the length scales of the self-assembled P123 structure and therefore causing the micro-morphology to break down during annealing. Alternative concepts include backfilling the mesopores with carbon or silica<sup>21</sup> or elaborate annealing and crystallisation protocols<sup>14</sup> to enhance temperature stability or the addition of preformed TiO<sub>2</sub> nanocrystals to decrease the crystallisation temperature<sup>22</sup> but to simultaneously achieve high crystallinity and structural integrity remains a challenge. Furthermore phase impurities have repeatedly been reported with finite amounts of TiO<sub>2</sub> (B) and traces of rutile.<sup>23</sup> Both these phases are less favorable for solar cell operation.<sup>24</sup> One of the main limiting factors is the relatively low molecular weight of the commercially available Pluronic compound. The resulting small pore sizes limit the infiltration of dye and hole-transporting phase, which poses a problem particularly for the assembly of solid-state devices.

Recently, copolymer systems of higher molecular weights such as poly[(ethylene-co-butylene)-*b*-(ethylene oxide)] (PHB-*b*-PEO) were introduced, which offer significantly thicker pore walls compared to P123-derived materials, leading to more stable structures during annealing at up to 700 °C for short annealing times (10 min).<sup>16,20</sup> The high molecular weight PI-*b*-PEO copolymer used in the present study exhibits several intrinsic characteristics which makes it well-suited as a structure-directing agent in polymer-derived inorganic nanostructures.<sup>11,25,26</sup> Most important are the high Flory-Huggins interaction parameter of PI-PEO blends of  $\chi(T) = 65/T + 0.125$  and the low glass transition temperatures of both blocks. The large degree of polymerisation of both blocks of the copolymer used in this study of  $N_{\text{PEO}} = 190$ , and  $N_{\text{PI}} = 400$  exceed values of conventional structure-directing agents and enable robust phase segregation which typically exhibits long-range order. In contrast to earlier studies using low molecular weight copolymers with long hydrophilic blocks,<sup>16,20</sup> the large value of  $N$  and the high volume fraction (76.9%) of the hydrophobic PI block

give rise to a porous network with large enough pores to facilitate the infiltration of the network with solid-state hole conducting materials<sup>27</sup> as well as yielding a highly porous inorganic material which is less susceptible to shrinkage and structural collapse. Furthermore, the  $sp^2$  hybridized carbon atoms in PI are converted to a carbonaceous scaffold under non-oxidising heating conditions, which helps to keep the mesostructure intact even at high temperatures.<sup>28,29</sup> The insolubility of PI-*b*-PEO in aqueous solvents poses, however, a challenge when used with hydrolytic sol-gel chemistries, particularly in thin film processing.

Here, we report a material synthesis route for the rapid manufacture of highly ordered titania films with a high degree of crystallinity. The use of an amphiphilic PI-*b*-PEO block copolymer enabled thin film deposition of highly ordered, temperature robust mesoporous titania without the need for time consuming synthesis protocols. Three aspects were studied with the aim to improve mesoporous anatase scaffolds for DSCs: (1) A solvent exchange was introduced in the synthesis procedure to improve the film processing and the formation the self-assembled mesostructure. (2) The time and temperature dependence of anatase formation was studied and correlated with the crystallite size, surface area, and conductivity of the mesoporous network. (3) Liquid and solid-state DSCs based on the anatase series from (2) were manufactured and their electronic properties are discussed in the context of crystallinity, porosity, and connectivity of the porous  $TiO_2$  scaffold.

## Results and discussion

### Structure formation and stability

In difference to Pluronic-based systems, PI-*b*-PEO is insoluble in water or ethanol. A typical approach for synthesising anatase  $TiO_2$  consists therefore of separately preparing a water-based sol containing a Ti salt or alkoxide and a solution of the block copolymer in tetrahydrofuran (THF). The two solutions are then mixed before allowing the solvents evaporate, which results in a self-assembled organic-inorganic hybrid schematically shown in Figure 1a. In thin film processing, the structure formation occurs on a much faster time scale. The differing boiling points of water and

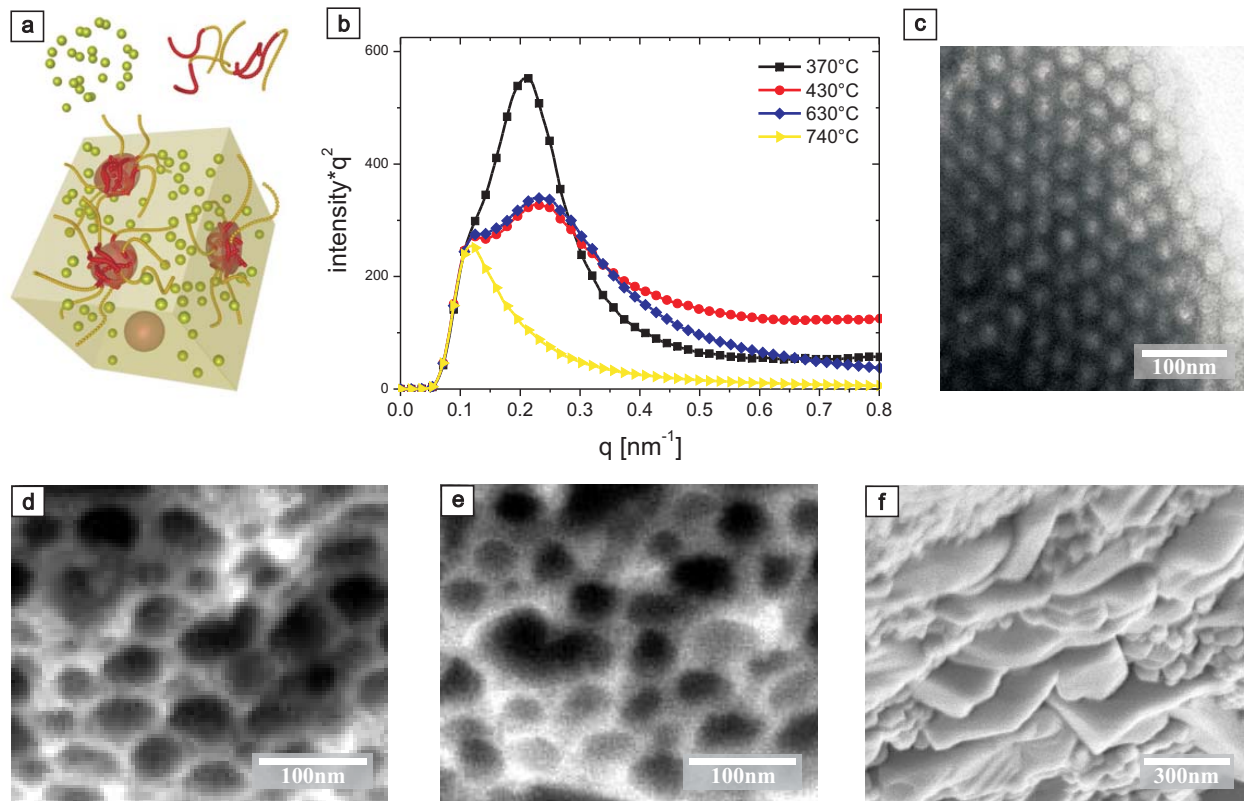


Figure 1: Film deposition and structural stability. (a) Hydrolytic TiO<sub>2</sub> sol when mixed with a PI-*b*-PEO solution is structure-directed by copolymer self-assembly, giving rise to nanostructured TiO<sub>2</sub> after high-temperature annealing. (b) Small-angle x-ray scattering (SAXS) spectra for copolymer-derived TiO<sub>2</sub> annealed at 370 °C (black squares), 430 °C (red circles), 630 °C (blue diamonds) and 740 °C (yellow triangles). The spectra are scaled in intensity to overlap in the 0 – 0.1 nm<sup>-1</sup> *q*-range. (c) TEM image of the ordered f.c.c. micellar hybrid film produced by spin-coating the redissolved material. Cross-sectional SEM images of the nanostructured TiO<sub>2</sub> films calcined in air at temperatures of (d) 430 °C and (e) 690 °C for 400 min. (f) Cross-sectional SEM image of a film annealed at 740 °C which resulted in the transformation from anatase to rutile and a subsequent loss of the mesopores.

the organic solvents therefore often lead to quenched morphologies with poor structure control. For high inorganic loadings, the low solubility of polymer in the water rich solvent mixture imposes another challenge. We have addressed these limitations by adding a solvent exchange step to the sample preparation procedure. The initial mixture was slowly dried in a Petri dish and the resulting hybrid material was directly redissolved in a mixture of 1-butanol and toluene in a ratio that allowed the formation of an azeotrope<sup>30</sup>(a solvent mixture of equal boiling point). The azeotrope dissolves both the hydrophilic and hydrophobic phases of the hybrid material while exhibiting a common high boiling point. This results in a better solubility of the polymer and titania sol and slower evaporation of the solvents, which gives rise to better ordered local structure and film formation of the dried hybrid material. Further experimental details about the redissolution step and its effect on the morphology of resulting films are given in the Supporting Information (SI).

Figure 1 demonstrates the structural control of this approach. The role of the amphiphilic block copolymer as structure-directing agent, organising the inorganic titania sol in a highly ordered network is illustrated in Figure 1a. Structural order after film deposition and during high temperature annealing was probed by small angle x-ray scattering (SAXS), shown in Figure 1b. The characteristic length-scale (*d*-spacing) of the self-assembled structure was 30 nm, shrinking to 27 nm after removal of the organic template for temperatures above 370 °C. The first-order peak at  $\sim 0.23 \text{ nm}^{-1}$  disappeared only at 740 °C, indicating a loss of structural order at this temperature. Electron microscopy confirmed these observations. Figure 1c shows a TEM image of a hybrid film before calcination, consistent with a face-centred-cubic (f.c.c.) micellar hybrid assembly. Note that this film was simply spin-coated from the 1-butanol/toluene solution without further time-consuming annealing procedures to promote phase separation. Cross-sectional SEM images of the calcined films in Figure 1 d-e show that the self-assembled morphology remained intact after calcination at temperatures of (d) 430 °C and (e) 690 °C for 400 min. The collapse of the pores observed at 740 °C is evidenced by the SEM cross-section in Figure 1f.

A micellar morphology consistent with a short-range f.c.c. order is observed for a number of different copolymer architectures and sol-loadings. This suggests that the micro-morphology origi-

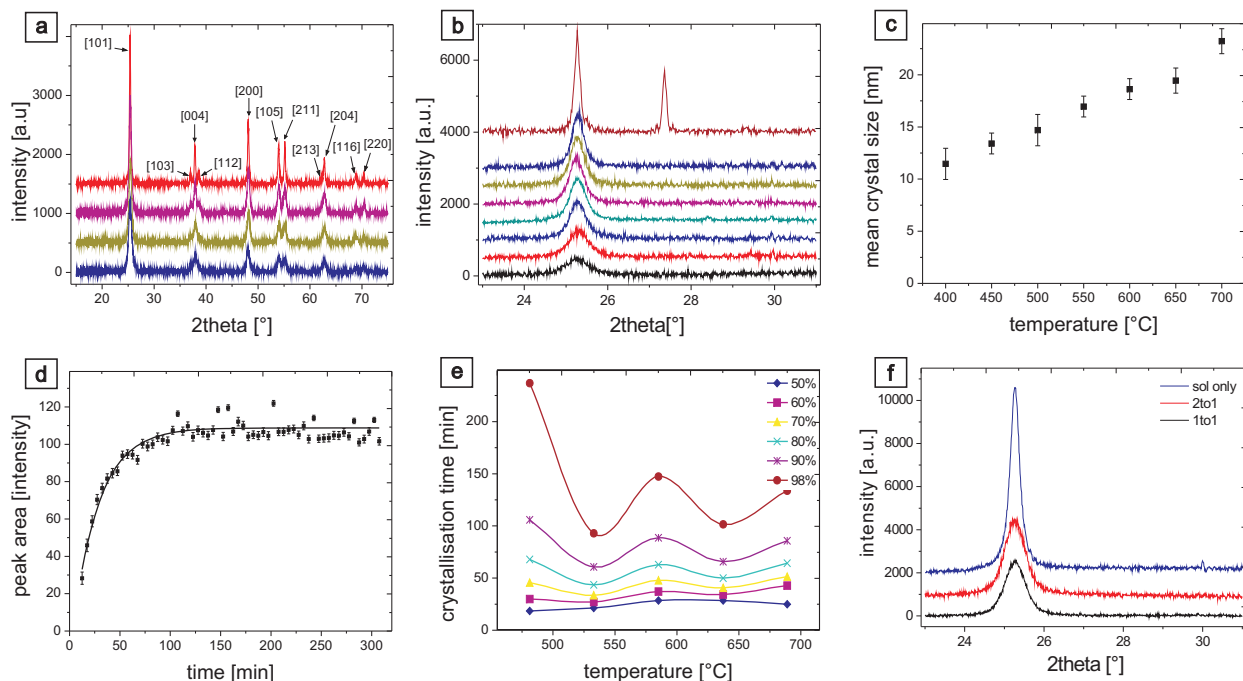


Figure 2: Crystallisation of TiO<sub>2</sub> anatase crystals in block-copolymer derived confinement (a) Wide angle x-ray diffraction scans of mesoporous films annealed at 400 °C, 500 °C, 600 °C, and 700 °C (bottom to top). (b) Anatase (101) crystal footprint as a function of crystallisation temperature after annealing for 400 min. From bottom to top: 400 °C to 700 °C in 50 °C increments (structurally intact), and 740 °C (collapsed structure). (c) Debye-Scherrer mean crystallite sizes after annealing for 400 min as a function of temperature. (d) Evolution of crystallinity by monitoring the peak area as a function of time at 530 °C. (e) Evolution of overall crystallinity with time as a function of temperature. (f) Dependence of anatase (101) peak on mass ratio of TiO<sub>2</sub> to block copolymer. From bottom to top; black: 1 to 1 mass ratio (mean crystallite size: 9.5 nm); red: 2 to 1 mass ratio (14.7 nm); blue: sol only (23.6 nm).

nates from the packing structures that probably already exist in solution. In contrast to structure formation in bulk samples produced by drop-casting (where an equilibrated microphase morphology is observed), spin-cast films are presumably kinetically hindered from forming a self-assembled morphology dictated by the copolymer architecture in the melt. Supported by our results discussed below, it is important to note that, despite the micellar assembly a 3D bicontinuous network of titania and pores is obtained with structure control (through the micellar size) on the 10-nm length scale. The robustness of the micellar morphology with respect to the various system parameters is an advantage, simplifying the comparison of differently produced samples.



## Crystallisation kinetics and crystal sizes

The overall crystallinity and crystallite size strongly influence charge transport properties of polycrystalline wide band-gap semiconductors and therefore play important roles in device applications. Annealing times and temperatures during crystal formation are obviously important in controlling these parameters. Figure 2a shows wide-angle x-ray scattering (WAXS) patterns of TiO<sub>2</sub> films annealed for 400 min at temperatures between 400 °C and 700 °C. Up to annealing temperatures of 700 °C, all reflections can be indexed to anatase (PDF 71-1167), confirming phase purity for these annealing conditions. The smaller angular range of Figure 2b shows the evolution of the width of the anatase (101) peak with temperature after an annealing time of 400 min. The Debye Scherrer analysis of the full-width at half maximum (FWHM) of the (101) peak was used to define the mean crystallite size of the polycrystalline assembly, shown in Figure 2c. The final crystallite size was found to be independent of the heating rate in the range of 1 – 10 °C/min. In contrast to phase purity up to 700 °C, a significant rutile content can be observed after annealing at 740 °C, evidenced by the appearance of the (110) peak at 27.3° (PDF 76-1940). A comparison of the SAXS and XRD results of Figure 1b and Figure 2b suggests that the structural collapse at 740 °C is caused by the stresses involved in the reconstructional transformation from anatase to rutile.

To investigate the time required for completion of the crystallisation process, we monitored the crystallite growth in-situ during the calcination process by x-ray diffraction. The observed diffraction range for  $2\theta$  between 22° and 32° (Cu K $\alpha$  radiation) contains the anatase (101) peak which was used for this analysis. A typical in-situ scan of TiO<sub>2</sub> during calcination at 530 °C is shown in Figure 2d, indicating completion of the crystallisation process after about 100 min.

The evolution of the overall crystallinity with time was determined by comparing, at each temperature, the area of the anatase peak with the peak area for an annealing time of 400 min, which was defined as 100% crystallinity. The result of this analysis is shown in Figure 2e, where the time required to reach values of the overall crystallinity of 50% - 98% is plotted as a function of temperature. While near-complete crystallinity (98%) was obtained after 100 – 150 min for temperatures between 530 °C and 690 °C, much longer times were needed for temperatures below

500 °C. In addition, the careful investigation of all WAXS samples in reflection (Figure 2a and b) and transmission (shown in the SI) showed no sign of an amorphous hump. Our results agree with a study by Fattakhova *et al.*<sup>20</sup> reporting the rapid disappearance of the amorphous signal for annealing temperatures between 550 °C and 650 °C. Based on our measurements, we conclude that the amorphous content in all our samples was very low when annealed above 400 °C for several hours.

The crystal growth kinetics in Figure 2e reveal further details. While the crystallite size of the fully crystalline material increases with increasing temperature, the time required to reach 98% crystallinity is a non-monotonous function of temperature. The two minima in the 98% curve in Figure 2e suggest that several different mechanisms govern the anatase crystallisation kinetics as a function of temperature. This is, however, not reflected in the final crystal sizes of Figure 2c. The slow crystallisation for temperatures below 500 °C is noteworthy because mesoporous TiO<sub>2</sub> employed in DSCs is often annealed at similarly low temperatures.

The crystal size is strongly influenced by the confinement of the organic template shown in Figure 2f for an annealing temperature of 500 °C. Doubling the weight ratio of polymer to hydrolytic sol leads to a decrease in crystallite size by  $\approx 30\%$ . In the absence of the organic structure directing agent much larger crystals ( $> 23$  nm) were observed. In addition, we have recently shown that the crystallization environment, tuned by the inorganic to organic ratio, is a decisive factor in determining the distribution of sub-bandgap electronic states and the associated electronic function in solid-state dye-sensitized solar cells.<sup>31</sup>

High resolution transmission electron microscopy (HRTEM) images of samples annealed at 400 °C and 650 °C are shown in Figure 3a and b, respectively. The sample annealed for 400 min at 400 °C shows a heterogeneous assembly of small crystallites of  $10 \pm 5$  nm. Increasing the temperature to 650 °C, leads to larger and more irregularly shaped crystals of around 20 nm, which probably derive from the coalescence of smaller grains. These results are consistent with the x-ray diffraction data analysis. The schematics in Figure 3c and d illustrate crystal growth in copolymer derived confinement at low and high temperatures, respectively.

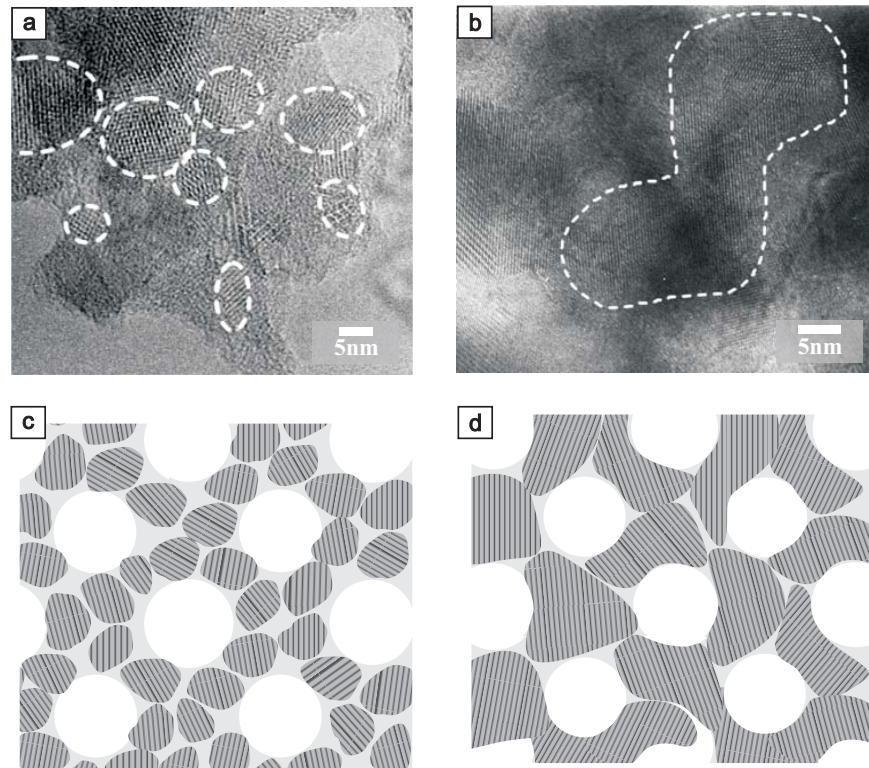


Figure 3: Crystallite assembly within the mesoporous network. High resolution transmission electron microscopy (HRTEM) images of samples annealed at (a) 400 °C and (b) 650 °C. White dotted lines are superimposed on the images to visualize individual crystallites. (a) Sample annealed at 400 °C: small, randomly oriented crystals significantly smaller than the lengthscale of the porous matrix are observed. (b) Sample annealed at 650 °C: crystal size exceeds the length scale of the confinement. Anisotropic growth within the network is likely. (c-d) Schematic illustrating crystallite size and orientation in copolymer derived networks at (c) 400 °C and (d) 650 °C.

### Effect of high temperature annealing on conductivity and device performance

Dye sensitised solar cells consist of a bicontinuous random anatase network with porosity on the 10-nm scale. A molecular layer of dye is adsorbed onto the network surface and the pores are filled with either a liquid electrolyte or a molecular or polymeric hole-conducting material (solid-state DSC). The performance of DSCs hinges on the interplay of efficient charge generation and separation combined with a near-lossless charge transport through the n- and p-type materials to the respective electrodes. The morphology and electrical conductivity of the anatase network is therefore of central importance.

Historically, copolymer-derived TiO<sub>2</sub> films have been restricted to low annealing temperatures

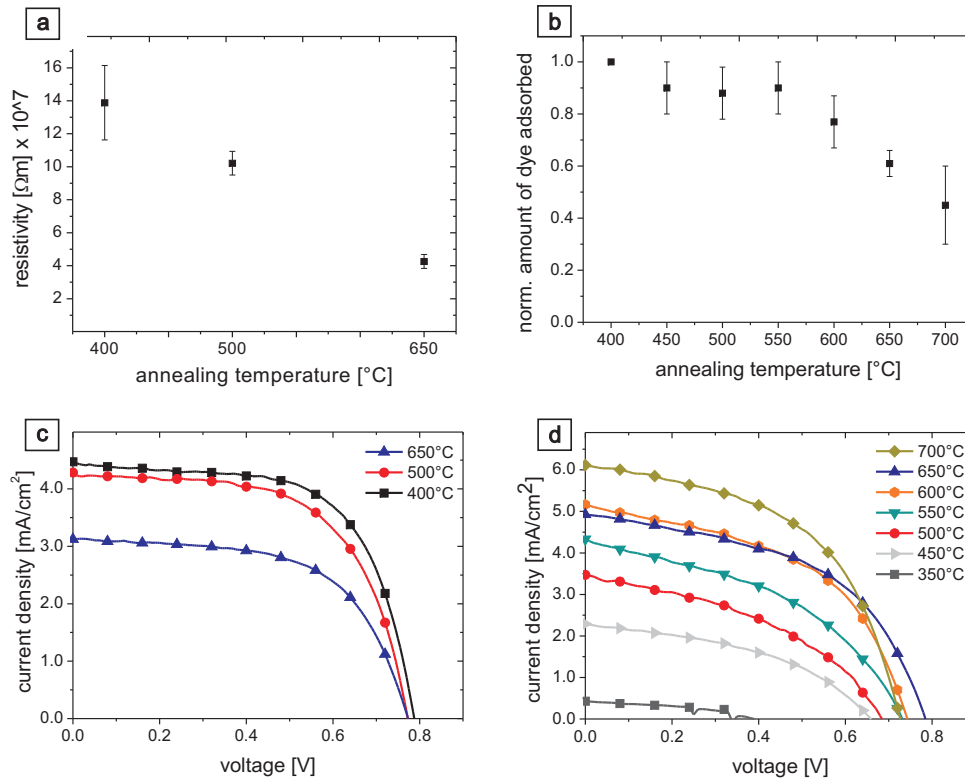


Figure 4: Effects of crystallinity on device performance. (a) Resistivity determined by impedance spectroscopy of 900 nm thick films annealed at 400  $^{\circ}\text{C}$ , 500  $^{\circ}\text{C}$ , and 650  $^{\circ}\text{C}$ . (b) Relative amount of dye adsorbed per unit area. The dye adsorption of the mesoporous film annealed at 400  $^{\circ}\text{C}$  was used as the baseline. (c) Current-voltage characteristics for liquid electrolyte DSC devices annealed at 400  $^{\circ}\text{C}$ , 500  $^{\circ}\text{C}$ , and 650  $^{\circ}\text{C}$ . (d) solid-state DSC performance of samples annealed at 350  $^{\circ}\text{C}$  to 700  $^{\circ}\text{C}$ . Higher temperatures led to a continuous increase in efficiency from 0.8% (450  $^{\circ}\text{C}$ ) to 2.5% (700  $^{\circ}\text{C}$ ) for 400 nm thick films sensitised with D102. Liquid and solid-state devices were characterised under standardised AM 1.5 illumination of 100  $\text{W}/\text{cm}^2$ . See the supporting information for a summary of all photovoltaic device performance parameters.

resulting in films which suffer from high resistivities. Since a low electron mobility has been identified as a limitation for the development of high-efficiency solid-state DSCs,<sup>9</sup> this material synthesis route is particularly interesting for applications where poor charge carrier transport limits the device performance. Anatase resistivity is expected to depend sensitively on the degree of crystallinity, crystallite size, and topology of the porous network,<sup>32,33</sup> all of which can be controlled by the present approach.

The annealing-temperature dependence of the resistivity of 900 nm thick mesoporous  $\text{TiO}_2$

films is shown in Figure 4a. The film resistivity was determined by impedance spectroscopy measurements done on complete, liquid electrolyte based devices. The obtained data was fitted to a transmission line equivalent circuit model adapted from Ref.<sup>34</sup> Increasing the annealing temperature from 400 °C to 650 °C reduced the resistivity by over a factor of 3. We note that the sheet resistance of the bare FTO substrate increased slightly over this temperature range. When analysing these results in the light of the crystallization data shown in Figure 2c, it is suggestive that film conductivity depends on the crystallite size, i.e. it is limited by the density of grain boundaries. This result illustrates the importance of annealing anatase at high temperatures for extended periods of time. Our results are in line with a recent study of Hartmann and coworkers who compared the photoelectrochemical properties of sol-gel derived and nanoparticle based electrodes. They associated enhanced electronic connectivity to the superior performance of sol-gel based materials.<sup>35</sup>

Figure 4b shows the annealing temperature dependence of the relative amount of adsorbed dye (N719) per unit area, which is a measure for the accessible surface area in the film. The dye adsorption of the mesoporous film annealed at 400 °C was used as the baseline. At this temperature a surface area of 82 m<sup>2</sup>/g was measured by nitrogen physisorption (BET). The results suggest that the specific accessible surface area varies only weakly in the 400–550 °C range, whereas it drops off for the highest annealing temperatures. Figure 4a and b illustrate a trade-off when choosing the optimal TiO<sub>2</sub> sintering temperature for DSC production. High temperature annealing leads to a larger crystallite size and therefore a coarser crystallinity of the anatase network with a smaller number of grain boundaries. This benefits charge transport through the network at the expense of accessible surface area for dye adsorption. The coarser crystallinity comes at the expense of a reduced surface area leading to a reduction in dye adsorption and therefore to a reduction in charge generation per unit volume.

This trade-off was further explored in liquid electrolyte and solid-state DSCs. For liquid electrolyte DSCs, TiO<sub>2</sub> films were annealed at temperatures ranging from 400 °C to 650 °C. In this study, 900 nm thick anatase films were used to avoid the formation of cracks which typically oc-

curs for thicker films. While devices annealed at 400 °C and 500 °C had very similar photon-to-electron conversion efficiencies (EQEs) with maxima of 22.6%, annealing at 650 °C resulted in a reduction of the  $\text{EQE}_{\text{max}}$  to 18.6%. This reduction in EQE most likely correlates with the reduced dye loading derived from Figure 4b. The corresponding current-voltage ( $J - V$ ) curves are shown in Figure 4c. While all devices had comparable open-circuit voltages  $V_{\text{oc}}$ , their short-circuit current  $J_{\text{sc}}$  decreased with increasing anatase annealing temperature. The related power conversion efficiencies  $\eta$  were 2.3 %, 2.0 % and 1.5 % for 400 °C, 500 °C, and 650 °C, respectively. The decrease in  $J_{\text{sc}}$  and  $\eta$  follows the trend in dye-adsorption (Figure 4b) and EQE. While the values for the anatase annealing temperatures of 400 °C and 500 °C are comparable, reflecting the plateau in Figure 4b, the reduced values for the 650 °C data-set correlates with the drop-off in specific surface area in Figure 4b for this temperature. This result is not surprising. In liquid cells, charge recombination is believed to be not a limiting factor as it occurs via a slow two-electron process.<sup>36</sup> The increased  $\text{TiO}_2$  conductivity does therefore not outweigh the loss in specific surface area for this cell type.

The situation is very different for solid-state DSCs. To this end, Figure 4d shows the  $J - V$  curves of solid-state DSCs employing the D102 dye and spiro-OMeTAD as hole-conducting medium (see Experimental Section for details on device assembly). 400 nm-thick  $\text{TiO}_2$  films were used. An increase in the sintering temperature in the range from 350 °C to 650 °C resulted in a continuous increase in all relevant device performance parameters ( $V_{\text{oc}}$ ,  $J_{\text{sc}}$ , FF, and  $\eta$ ). The decrease in  $V_{\text{oc}}$  for samples annealed at 700 °C might be partially due to the fact that the sheet resistance of the FTO doubled to 40  $\Omega/\square$  at these high temperatures. Nevertheless, the power conversion efficiency increased from 0.78% for 450 °C to 2.48% for samples annealed at 700 °C. This is in contrast to earlier Pluronic-based approaches, where annealing is typically limited to 450 °C.<sup>17</sup> Since the specific surface area and dye loading are reduced for the highest anatase annealing temperatures (Figure 4b), these results imply that the solid-state DSCs strongly benefit from the increased  $\text{TiO}_2$  conductivity as evidenced in Figure 4a. This result underlines the importance of anatase conductivity for solid-state DSCs, the performance of which is limited by charge

recombination. This effect is expected to be even more pronounced in thicker devices.

We are currently working on techniques to increase the thickness of crack free films which should enable us to increase the light absorption while maintaining the excellent conductivity afforded by our anatase synthesis route. We note that the  $\text{TiO}_2$  films were not post treated with  $\text{TiCl}_4$  further underlining the quality of the anatase produced by this approach. The for their thickness unusual high efficiencies of the solid-state DSCs also prove that the titania network, though micellar, is well interconnected<sup>37</sup> and allows sufficient pore infiltration with a solid-state hole conductor.

## Conclusions

We present a facile but powerful method for the synthesis of highly conductive mesoporous  $\text{TiO}_2$  via sol-gel chemistry. In contrast to earlier work, our method maintains structural integrity of the porous titania scaffold up to  $700^\circ\text{C}$ , enabling to study the effect of high annealing temperatures on device performance of DSCs. The self-assembling block-copolymer PI-*b*-PEO is highly effective in controlling anatase crystallisation in mesoporous networks. It rapidly assembles the  $\text{TiO}_2$  sol into an ordered spatial confinement which promotes crystallite growth replicating the organic matrix. The resulting anatase network consists of relatively large crystallites, while maintaining the structural integrity dictated by the polymer scaffold.

When used in DSCs, the control over anatase crystal parameters afforded by our protocol presents an interesting dilemma: while anatase conductivity is markedly improved by high temperature annealing, this comes at the expense of specific surface area of the mesoporous scaffold. For liquid DSCs in which charge carrier recombination is not a limitation even for thick cells, the use of high temperature annealed anatase films therefore has a detrimental effect on device performance. In solid-state DSCs, on the other hand, the reduced dye loading of the less grainy  $\text{TiO}_2$  network is outweighed by the improved anatase conductivity, leading to an increase in power conversion efficiency of the cell employing anatase annealed at  $700^\circ\text{C}$  by a factor of 3 compared to materials made by the previously established route.

In summary, we have demonstrated a DSC device manufacture protocol that combines the detailed control over anatase mesomorphology on the 20-nm length scale with simultaneous control over anatase crystallinity. This protocol is highly promising for the improvement of device efficiency of solid-state DSCs. Future work will now concentrate on the manufacture of thicker, crack free films, to fully exploit the potential of this methodology.

## Experimental section

### Synthesis

Titania containing sol was synthesised by quickly adding 0.69 ml of HCl (37 %) into 1 ml of titanium ethoxide (purum) under vigorous stirring at ambient conditions.<sup>38</sup> 0.873 ml sol was subsequently mixed with 0.1g PI-*b*-PEO copolymer ( $M_n = 35.7$  g/mol, 23 wt% PEO<sup>39</sup>) in 7 ml THF (99.97%, Fisher) and slowly evaporated in a Petri dish at 50 °C before the hybrid material was redissolved in an azeotrope solvent mixture of toluene (apolar, 99,8%) and 1-butanol (polar, 99%). This step is undertaken since the hydrolytic sol contains a large amount of water and ethanol (over 70 wt%), which is unfavourable for the simultaneous continuous evaporation of the hydrophobic and hydrophilic solution components (see SI). A 20 wt% solution was then spin-coated (5 s, 1000 rpm) on a (100) silicon substrate and the sample was dried for several hours at room temperature, resulting in 1 µm thick films. For bulk material, the reconstituted solution was evaporated in a petri dish. All residual solvent was subsequently evaporated by heating the samples in a tube furnace at 130 °C followed by calcination in a tube furnace or a X-ray diffractometer with an integrated oven (Bruker D8 Advance) employing a heating rate of 10 °C/min unless otherwise stated.

### Wide-angle x-ray scattering

Wide angle x-ray scattering experiments during in-situ heating were carried out using a Bruker D8 Advance diffractometer in an angular range of 22° – 32° with a step size of 0.0143° and a total scan



time of 5 min. A heating rate of 10 °C/min was used unless otherwise stated. Samples were measured during annealing in air for up to 7 hours, representing 84 consecutive x-ray scans. Because of its crystal orientation, the single crystalline silicon substrate is not expected to contribute to a signal in the observed angular range. The measurements covered a temperature range between 380 °C and 740 °C in intervals of around 50 °C. The obtained raw data was corrected for the  $\text{CuK}_{\alpha 2}$  radiation by the Bruker software EVA. To obtain the peak broadening caused by the size of the anatase crystallites, a Voigt function was fitted to the peaks. The peak width (full width at half maximum) of the Lorentzian and the Gaussian parts of the Voigt function were determined by the approximation of Olivero and Longbothum.<sup>40</sup> The peak width was then corrected for machine broadening by subtracting (by deconvolution) the broadening of a monocrystalline silicon reference sample. The Debye-Scherrer equation was subsequently employed to obtain a mean crystallite diameter of the peak broadening.<sup>41</sup> Like in similar studies, the dimensionless number  $K = 0.89$  was used as Debye-Scherrer constant.<sup>19,42</sup> X-ray diffraction of separately annealed samples was carried out with a Philips PW1830 Generator 3a.

### **Small-angle X-ray scattering (SAXS)**

Small-angle x-ray scattering of  $\text{CuK}_{\alpha}$  radiation was collected in transmission geometry at a sample-detector distance of 1.05 m (Bruker AXS Nanostar, Karlsruhe, Germany). Acquisition times of 7500 s were used. The scattered intensity was collected using a 2-dimensional Hi-Star gas-filled wire detector with  $1024 \times 1024$  channels and the incident beam-path directed towards its centre. A lead beam-stop was suspended in front of the detector in the beam path, to prevent damage due to unattenuated X-rays; this obscured any scattering below  $q = 0.08 \text{ nm}^{-1}$ . 'Background' scans were performed with an empty camera; this was used to correct the scattering measured for specimens, after allowing for transmission. In each case, the scattering patterns were found to be isotropic (i.e. no preferred orientation). Radial scattering intensity profiles were obtained by averaging over the azimuthal angle (from 0 to 360°) with 0.005° increments in scattering angle.

## Transmission electron microscopy (TEM)

Samples annealed at different temperatures were dispersed on holey carbon coated TEM copper grids and imaged using a FEI Tecnai F20 microscope (200 kV). For high resolution transmission electron microscopy, a Jeol JEM 4000EX (400 kV) was used.

## Impedance spectroscopy

A Gamry Reference 600 potentiostat with the EIS300 software package was employed to measure impedance spectra. Spectra were collected in the dark under forward bias that is adjusted to match the open circuit potential under AM 1.5. The AC amplitude used was 10 mV and the spectra were collected from 10 mHz to 10 kHz with 10 frequencies per decade. The analysis of the spectra were performed using ZView v2.8 using a circuit model adapted from Ref.<sup>34</sup>

## Dye absorption measurements

In order to quantify the accessible surface area for dye sensitization, dye desorption studies were carried out similar to Neale *et al.*<sup>43</sup> Mesoporous TiO<sub>2</sub> films were immersed in a 0.5 mM solution of cis-di(thiocyanato)-bis(2,2'-bipyridyl-4-carboxylate-4'-carboxylic acid)-ruthenium(II) (termed N719) in a mixture of acetonitrile:*tert*-butyl alcohol (volume ratio 1:1) and kept in the dark for 16 hours at room temperature. The samples were then thoroughly rinsed with acetonitrile and subsequently submerged into a 1.0 mM KOH solution (3 ml) for 3 hours to fully desorb the dye. The absorbance of the resulting light pink solutions was measured with an UV-vis spectrophotometer (HP 8453 UV/vis spectrophotometer, wavelength range 190 – 1100 nm, 1 nm slit width, 0.03% stray light). The relative amount of dye adsorbed was determined by comparing the peak height of the respective solution with the reference obtained from desorption of the film annealed at 400 °C.

## Liquid electrolyte DSC assembly

Fluorine doped SnO<sub>2</sub> (FTO) coated glass sheets (Nipon Sheet Glass, TEC15) were manually cleaned with Hellmanex soap, acetone, and isopropanol followed by 10 min in an O<sub>2</sub> plasma etcher. 900 nm thick anatase films were then spin-cast onto the substrates and annealed as described above. The samples were sensitised with N719 as described above.

The counter electrodes used for these devices were sheets of pre-drilled platinized FTO glass. The platinization was carried out by coating the FTO with hexachloroplatinic (IV) acid from an anhydrous isopropanol solution (50 mM) followed by heating to 450 °C for 15 min. The dyed TiO<sub>2</sub> electrodes were washed in acetonitrile, dried and assembled in a sandwich type cell configuration with the platinized counter electrodes, using a ‘hot-melt’ 50 µm thick surlyn spacer (Dupont) to seal the working and counter electrode together. A drop of ‘Robust’ liquid electrolyte (0.8 M PMII, 0.15 M iodine, 0.1 M GuNCS, and 0.5 M NMBI in 3-methoxypropionitrile)<sup>44</sup> was dispensed into a hole in the counter electrode and the cell was filled via vacuum backfilling and sealed with polyimide tape (Dupont).

## Solid-state DSC assembly

Solid-state DSCs were fabricated using the method outlined in Ref.<sup>45</sup> The TiO<sub>2</sub> films were dye-sensitized with D102 (indolin-based organic dye) for 1 hour. Spiro-OMeTAD (2,2',7,7'-tetrakis(N,N-di-methoxyphenylamine)-9,9'-spirobifluorene) dissolved in chlorobenzene was used as the hole-transporting material (HTM), with tert-butyl pyridine (tBP) and bis(trifluoromethyl-sulfonyl)amine lithium salt (Li-TFSI) (dissolved separately in acetonitrile) used as additives for improved device performance.<sup>45</sup> Finally, 150 nm thick silver electrodes were evaporated over the HTM layer under high vacuum (10<sup>-6</sup> mbar) to complete the devices.

## DSC characterisation

The solar cells were measured under AM 1.5 simulated sun light generated by a 300 W Oriel solar simulator. The power of the simulated light was measured using a calibrated Si photo diode (Fraunhofer Institute for Solar Energy Systems). The mismatch factor to the solar spectrum was calculated over the entire spectral response region of both the test solar cells and calibration diode following the method of Seaman.<sup>46</sup> The active area of the DSCs was 0.13 cm<sup>2</sup>. The current-voltage measurements were recorded by a Keithley 237 sourcemeter connected to a computer.

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